

Quad, 64 Tap, Digitally Controlled Potentiometer (XDCP™)

FEATURES

- Quad—4 separate pots, 64 taps/pot
- Nonvolatile storage of wiper position
- Four Nonvolatile Data Registers for Each Pot
- 16-bytes of EEPROM memory
- SPI serial interface
- $R_{Total} = 10k\Omega$
- Wiper resistance = 150Ω typical
- Standby current < $1\mu A$ (total package)
- Operating current < $400\mu A$ max.
- $V_{CC} = 2.7V$ to $5V$
- Packages—24 Ld TSSOP and SOIC
- 100 year data retention
- Pb-free plus anneal available (RoHS compliant)

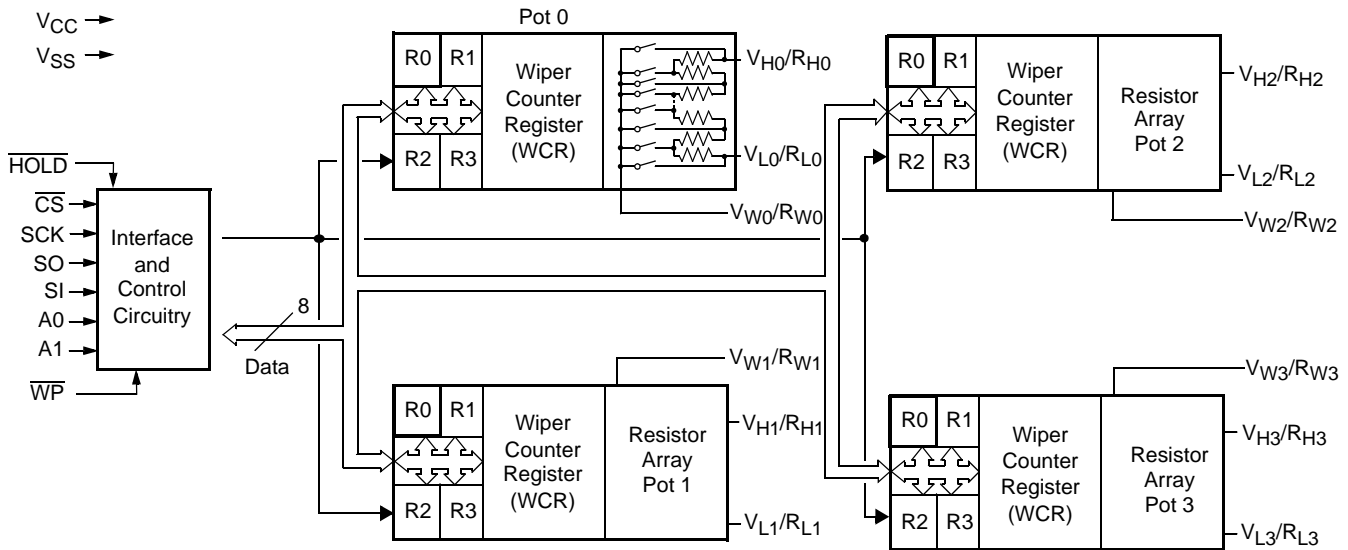
DESCRIPTION

The X9401 integrates 4 digitally controlled potentiometers (XDCP) on a monolithic CMOS integrated microcircuit.

The digitally controlled potentiometer is implemented using 64 resistive elements in a series array. Between each element are tap points connected to the wiper terminal through switches. The position of the wiper on the array is controlled by the user through the SPI bus interface. Each potentiometer has associated with it a volatile Wiper Counter Register (WCR) and 4 nonvolatile Data Registers (DR0:DR3) that can be directly written to and read by the user. The contents of the WCR controls the position of the wiper on the resistor array through the switches. Power-up recalls the contents of DR0 to the WCR.

The XDCP can be used as a three-terminal potentiometer or as a two-terminal variable resistor in a wide variety of applications including control, parameter adjustments, and signal processing.

BLOCK DIAGRAM



X9401

Ordering Information

PART NUMBER	PART MARKING	V _{CC} LIMITS (V)	POTENTIOMETER ORGANIZATION (k Ω)	TEMP RANGE (°C)	PACKAGE
X9401WS24*	X9401WS	5 \pm 10%	10	0 to 70	24 Ld SOIC (300 mil)
X9401WS24Z* (Note)	X9401WS Z			0 to 70	24 Ld SOIC (300 mil) (Pb-free)
X9401WS24I*	X9401WS I			-40 to 85	24 Ld SOIC (300 mil)
X9401WS24IZ* (Note)	X9401WS Z I			-40 to 85	24 Ld SOIC (300 mil) (Pb-free)
X9401WV24*	X9401WV			0 to 70	24 Ld TSSOP (4.4mm)
X9401WV24Z* (Note)	X9401WV Z			0 to 70	24 Ld TSSOP (4.4mm) (Pb-free)
X9401WV24I*	X9401WV I			-40 to 85	24 Ld TSSOP (4.4mm)
X9401WV24IZ* (Note)	X9401WV Z I			-40 to 85	24 Ld TSSOP (4.4mm) (Pb-free)
X9401WS24-2.7*	X9401WS F	2.7 to 5.5	2.5	0 to 70	24 Ld SOIC (300 mil)
X9401WS24Z-2.7* (Note)	X9401WS Z F			0 to 70	24 Ld SOIC (300 mil) (Pb-free)
X9401WS24I-2.7*	X9401WS G			-40 to 85	24 Ld SOIC (300 mil)
X9401WS24IZ-2.7* (Note)	X9401WS Z G			-40 to 85	24 Ld SOIC (300 mil) (Pb-free)
X9401WV24-2.7*	X9401WV F			0 to 70	24 Ld TSSOP (4.4mm)
X9401WV24Z-2.7* (Note)	X9401WV Z F			0 to 70	24 Ld TSSOP (4.4mm) (Pb-free)
X9401WV24I-2.7*	X9401WV G			-40 to 85	24 Ld TSSOP (4.4mm)
X9401WV24IZ-2.7* (Note)	X9401WV Z G			-40 to 85	24 Ld TSSOP (4.4mm) (Pb-free)
X9401YS24I-2.7	X9401YS G			-40 to 85	24 Ld SOIC (300 mil)
X9401YV24I-2.7	X9401YV G			-40 to 85	24 Ld TSSOP (4.4mm)

*Add "T1" suffix for tape and reel.

NOTE: Intersil Pb-free plus anneal products employ special Pb-free material sets; molding compounds/die attach materials and 100% matte tin plate termination finish, which are RoHS compliant and compatible with both SnPb and Pb-free soldering operations. Intersil Pb-free products are MSL classified at Pb-free peak reflow temperatures that meet or exceed the Pb-free requirements of IPC/JEDEC J STD-020.

PIN NAMES

Symbol	Description
SCK	Serial Clock
SI, SO	Serial Data
A ₀ - A ₁	Device Address
V _{H0} /R _{H0} - V _{H3} /R _{H3} , V _{L0} /R _{L0} - V _{L3} /R _{L3}	Potentiometers (terminal equivalent)
V _{W0} /R _{W0} - V _{W1} /R _{W1}	Potentiometers (wiper equivalent)
\overline{WP}	Hardware Write Protection
V _{CC}	System Supply Voltage
V _{SS}	System Ground
NC	No Connection

DEVICE DESCRIPTION

The X9401 is a highly integrated microcircuit incorporating four resistor arrays and their associated registers and counters and the serial interface logic providing direct communication between the host and the XDCP potentiometers.

Serial Interface

The X9401 supports the SPI interface hardware conventions. The device is accessed via the SI input with data clocked in on the rising SCK. \overline{CS} must be LOW and the \overline{HOLD} and \overline{WP} pins must be HIGH during the entire operation.

The SO and SI pins can be connected together, since they have three state outputs. This can help to reduce system pin count.

Array Description

The X9401 is comprised of four resistor arrays. Each array contains 63 discrete resistive segments that are connected in series. The physical ends of each array are equivalent to the fixed terminals of a mechanical potentiometer (V_H/R_H and V_L/R_L inputs).

At both ends of each array and between each resistor segment is a CMOS switch connected to the wiper (V_W/R_W) output. Within each individual array only one switch may be turned on at a time.

These switches are controlled by a Wiper Counter Register (WCR). The six bits of the WCR are decoded to select, and enable, one of sixty-four switches.

Wiper Counter Register (WCR)

The X9401 contains four Wiper Counter Registers, one for each XDCP potentiometer. The WCR is equivalent to a serial-in, parallel-out register/counter with its outputs decoded to select one of sixty-four switches along its resistor array. The contents of the WCR can be altered in four ways: it may be written directly by the host via the Write Wiper Counter Register instruction (serial load); it may be written indirectly by transferring the contents of one of four associated data registers via the XFR Data Register or Global XFR Data Register instructions (parallel load); it can be modified one step at a time by the Increment/Decrement instruction. Finally, it is loaded with the contents of its data register zero (R₀) upon power-up.

The Wiper Counter Register is a volatile register; that is, its contents are lost when the X9401 is powered-down. Although the register is automatically loaded with the value in R₀ upon power-up, this may be different from the value present at power-down. The wiper position must be stored in R₀ to insure restoring the wiper position after power-up.

Data Registers

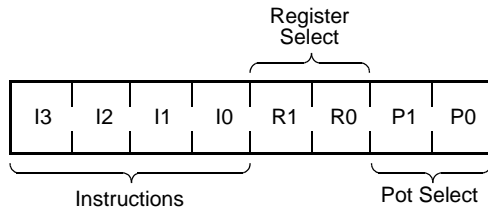
Each potentiometer has four 6-bit nonvolatile data registers. These can be read or written directly by the host. Data can also be transferred between any of the four data registers and the associated Wiper Counter Register. All operations changing data in one of the data registers is a nonvolatile operation and will take a maximum of 10ms.

If the application does not require storage of multiple settings for the potentiometer, the data registers can be used as memory locations for system parameters or user preference data.

Data Register Detail

(MSB)				(LSB)	
D5	D4	D3	D2	D1	D0
NV	NV	NV	NV	NV	NV

Figure 2. Instruction Byte Format



The four high order bits of the instruction byte specify the operation. The next two bits (R_1 and R_0) select one of the four registers that is to be acted upon when a register oriented instruction is issued. The last two bits (P_1 and P_0) selects which one of the four potentiometers is to be affected by the instruction.

Four of the ten instructions are two bytes in length and end with the transmission of the instruction byte. These instructions are:

- XFR Data Register to Wiper Counter Register—This transfers the contents of one specified Data Register to the associated Wiper Counter Register.
- XFR Wiper Counter Register to Data Register—This transfers the contents of the specified Wiper Counter Register to the specified associated Data Register.
- Global XFR Data Register to Wiper Counter Register—This transfers the contents of all specified Data Registers to the associated Wiper Counter Registers.
- Global XFR Wiper Counter Register to Data Register—This transfers the contents of all Wiper Counter Registers to the specified associated Data Registers.

The basic sequence of the two byte instructions is illustrated in Figure 3. These two-byte instructions exchange data between the WCR and one of the data registers. A transfer from a data register to a WCR is essentially a write to a static RAM, with the static RAM controlling the wiper position. The response of the wiper to this action will be delayed by t_{WRL} . A transfer from the WCR (current wiper position), to a data register is a write to nonvolatile memory and takes a minimum of t_{WR} to complete. The transfer can occur between one of the four potentiometers and one of its associated registers; or it may occur globally, where the transfer occurs between all potentiometers and one associated register.

Five instructions require a three-byte sequence to complete. These instructions transfer data between the host and the X9401; either between the host and one of the data registers or directly between the host and the Wiper Counter Register. These instructions are:

- Read Wiper Counter Register—read the current wiper position of the selected pot,
- Write Wiper Counter Register—change current wiper position of the selected pot,
- Read Data Register—read the contents of the selected data register;
- Write Data Register—write a new value to the selected data register.
- Read Status—This command returns the contents of the WIP bit which indicates if the internal write cycle is in progress.

The sequence of these operations is shown in Figure 4 and Figure 5.

The final command is Increment/Decrement. It is different from the other commands, because it's length is indeterminate. Once the command is issued, the master can clock the selected wiper up and/or down in one resistor segment steps; thereby, providing a fine tuning capability to the host. For each SCK clock pulse (t_{HIGH}) while SI is HIGH, the selected wiper will move one resistor segment towards the V_H/R_H terminal. Similarly, for each SCK clock pulse while SI is LOW, the selected wiper will move one resistor segment towards the V_L/R_L terminal. A detailed illustration of the sequence and timing for this operation are shown in Figure 6 and Figure 7.

Figure 3. Two-Byte Command Sequence

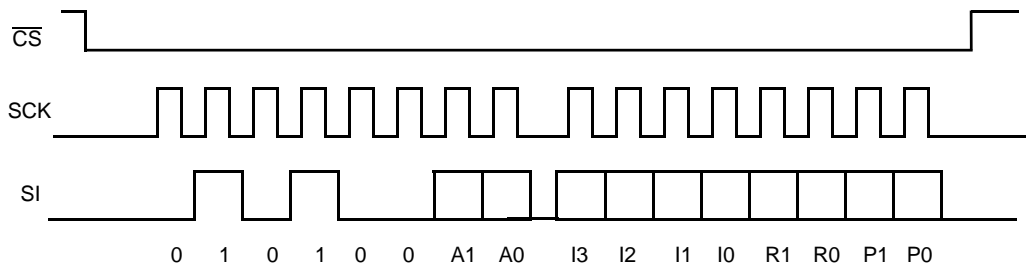


Figure 4. Three-Byte Command Sequence (Write)

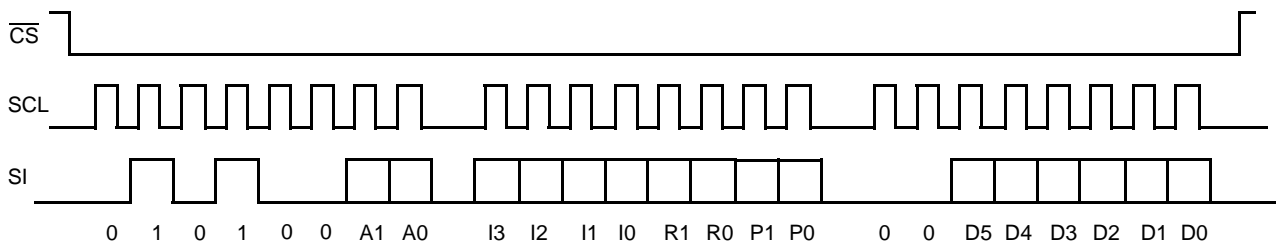


Figure 5. Three-Byte Command Sequence (Read)

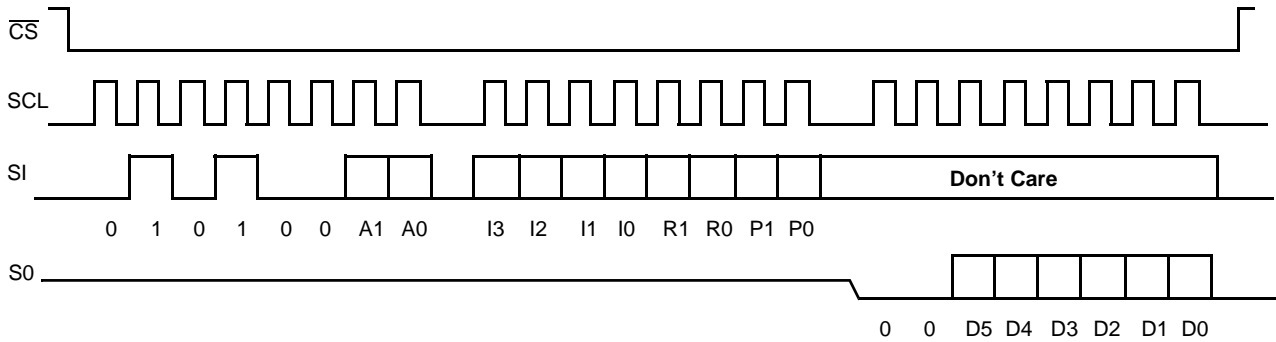


Figure 6. Increment/Decrement Command Sequence

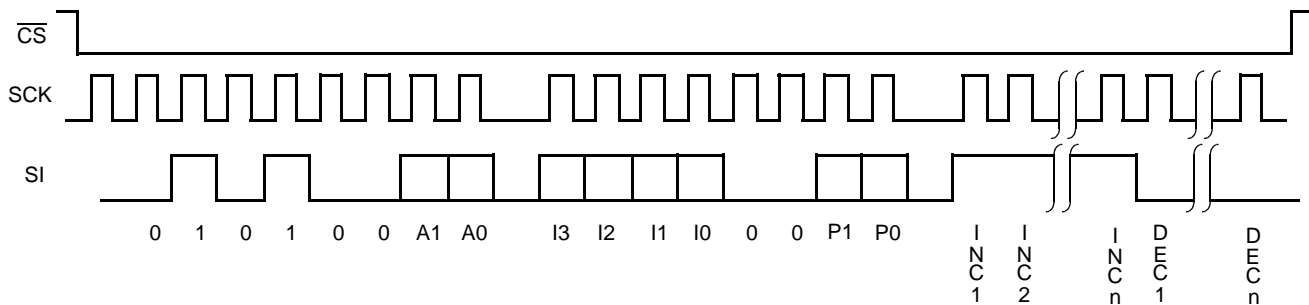


Figure 7. Increment/Decrement Timing Limits

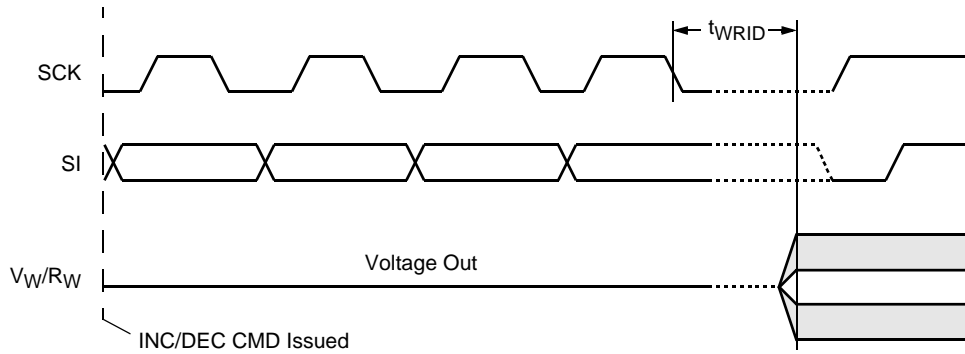


Table 1. Instruction Set

Instruction	Instruction Set								Operation
	I ₃	I ₂	I ₁	I ₀	R ₁	R ₀	P ₁	P ₀	
Read Wiper Counter Register	1	0	0	1	0	0	P ₁	P ₀	Read the contents of the Wiper Counter Register pointed to by P ₁ - P ₀
Write Wiper Counter Register	1	0	1	0	0	0	P ₁	P ₀	Write new value to the Wiper Counter Register pointed to by P ₁ - P ₀
Read Data Register	1	0	1	1	R ₁	R ₀	P ₁	P ₀	Read the contents of the Data Register pointed to by P ₁ - P ₀ and R ₁ - R ₀
Write Data Register	1	1	0	0	R ₁	R ₀	P ₁	P ₀	Write new value to the Data Register pointed to by P ₁ - P ₀ and R ₁ - R ₀
XFR Data Register to Wiper Counter Register	1	1	0	1	R ₁	R ₀	P ₁	P ₀	Transfer the contents of the Data Register pointed to by R ₁ - R ₀ to the Wiper Counter Register pointed to by P ₁ - P ₀
XFR Wiper Counter Register to Data Register	1	1	1	0	R ₁	R ₀	P ₁	P ₀	Transfer the contents of the Wiper Counter Register pointed to by P ₁ - P ₀ to the Register pointed to by R ₁ - R ₀
Global XFR Data Register to Wiper Counter Register	0	0	0	1	R ₁	R ₀	0	0	Transfer the contents of the Data Registers pointed to by R ₁ - R ₀ of all four pots to their respective Wiper Counter Register
Global XFR Wiper Counter Register to Data Register	1	0	0	0	R ₁	R ₀	0	0	Transfer the contents of all Wiper Counter Registers to their respective data Registers pointed to by R ₁ - R ₀ of all four pots
Increment/Decrement Wiper Counter Register	0	0	1	0	0	0	P ₁	P ₀	Enable Increment/decrement of the Wiper Counter Register pointed to by P ₁ - P ₀
Read Status (WIP bit)	0	1	0	1	0	0	0	1	Read the status of the internal write cycle, by checking the WIP bit.

Instruction Format

- Notes:** (1) "A1 ~ A0": stands for the device addresses sent by the master.
 (2) WPx refers to wiper position data in the Counter Register
 (3) "I": stands for the increment operation, SI held HIGH during active SCK phase (high).
 (4) "D": stands for the decrement operation, SI held LOW during active SCK phase (high).

Read Wiper Counter Register (WCR)

\overline{CS} Falling Edge	device type identifier				device addresses				instruction opcode				WCR addresses				wiper position (sent by X9401 on SO)							\overline{CS} Rising Edge		
	0	1	0	1	0	0	A	A	1	0	0	1	0	0	P	P	0	0	W	W	W	W	W		W	W
							1	0							1	0			P	P	P	P	P	P	P	
							1	0							1	0			5	4	3	2	1	0		

Write Wiper Counter Register (WCR)

\overline{CS} Falling Edge	device type identifier				device addresses				instruction opcode				WCR addresses				Data Byte (sent by Host on SI)							\overline{CS} Rising Edge		
	0	1	0	1	0	0	A	A	1	0	1	0	0	0	P	P	0	0	W	W	W	W	W		W	W
							1	0							1	0			P	P	P	P	P	P	P	
							1	0							1	0			5	4	3	2	1	0		

Read Data Register (DR)

\overline{CS} Falling Edge	device type identifier				device addresses				instruction opcode				DR and WCR addresses				Data Byte (sent by X9401 on SO)							\overline{CS} Rising Edge		
	0	1	0	1	0	0	A	A	1	0	1	1	R	R	P	P	0	0	W	W	W	W	W		W	W
							1	0							1	0			P	P	P	P	P	P	P	
							1	0							1	0			5	4	3	2	1	0		

Write Data Register (DR)

\overline{CS} Falling Edge	device type identifier				device addresses				instruction opcode				DR and WCR addresses				Data Byte (sent by host on SI)							\overline{CS} Rising Edge	HIGH-VOLTAGE WRITE CYCLE		
	0	1	0	1	0	0	A	A	1	1	0	0	R	R	P	P	0	0	W	W	W	W	W			W	W
							1	0							1	0			P	P	P	P	P	P	P		
							1	0							1	0			5	4	3	2	1	0			

Transfer Data Register (DR) to Wiper Counter Register (WCR)

\overline{CS} Falling Edge	device type identifier				device addresses				instruction opcode				DR and WCR addresses				\overline{CS} Rising Edge								
	0	1	0	1	0	0	A	A	1	1	0	1	R	R	P	P									
							1	0							1	0			1	0					

ABSOLUTE MAXIMUM RATINGS

Temperature under bias -65°C to +135°C
 Storage temperature -65°C to +150°C
 Voltage on SCK, SCL or any address
 input with respect to V_{SS}..... -1V to +7V
 $\Delta V = |(V_H - V_L)|$ 5.5V
 Lead temperature (soldering, 10s) 300°C

COMMENT

Stresses above those listed under “Absolute Maximum Ratings” may cause permanent damage to the device. This is a stress rating only; the functional operation of the device (at these or any other conditions above those listed in the operational sections of this specification) is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

RECOMMENDED OPERATING CONDITIONS

Temp	Min.	Max.
Commercial	0°C	+70°C
Industrial	-40°C	+85°C

Device	Supply Voltage (V _{CC}) Limits
X9401	5V ± 10%
X9401-2.7	2.7V to 5.5V

ANALOG CHARACTERISTICS (Over recommended operating conditions unless otherwise stated.)

Symbol	Parameter	Limits				Test Condition
		Min.	Typ.	Max.	Unit	
R _{TOTAL}	End to end resistance	-20		+20	%	
	Power rating			50	mW	25°C, each pot
I _W	Wiper current	-6		+6	mA	
R _W	Wiper resistance		150	500	Ω	Wiper Current = ± 3mA
V _{TERM}	Voltage on any V _H or V _L Pin	V _{SS}		V _{CC}	V	V _{SS} = 0V
	Noise		-120		dBV	Ref: 1kHz
	Resolution		1.6		%	
	Absolute linearity ⁽¹⁾	-1		+1	MI ⁽³⁾	V _{w(n)} (actual) - V _{w(n)} (expected)
	Relative linearity ⁽²⁾	-0.2		+0.2	MI ⁽³⁾	V _{w(n+1)} - [V _{w(n)} + MI]
	Temperature coefficient of R _{TOTAL}		±300		ppm/°C	
	Ratiometric temp. coefficient			±20	ppm/°C	
C _H /C _L /C _W	Potentiometer capacitances		10/10/25		pF	See Macro model
I _{AL}	R _H , R _L , R _W leakage current		0.1	10	μA	V _{IN} = V _{SS} to V _{CC} . Device is in stand-by mode.

POWER-UP AND DOWN REQUIREMENTS

There are no restrictions on the power-up or power-down conditions of V_{CC} and the voltages applied to the potentiometer pins provided that V_{CC} is always more positive than or equal to V_H, V_L, and V_W, i.e., V_{CC} ≥ V_H, V_L, V_W. The V_{CC} power-up spec is always in effect.

- Notes:** (1) Absolute linearity is utilized to determine actual wiper voltage versus expected voltage as determined by wiper position when used as a potentiometer.
 (2) Relative linearity is utilized to determine the actual change in voltage between two successive tap positions when used as a potentiometer. It is a measure of the error in step size.
 (3) MI = RTOT/63 or (V_H - V_L)/63, single pot

D.C. OPERATING CHARACTERISTICS (Over the recommended operating conditions unless otherwise specified.)

Symbol	Parameter	Limits				Test Conditions
		Min.	Typ.	Max.	Unit	
I _{CC1}	V _{CC} supply current (active)			400	μA	f _{SCK} = 2MHz, SO = Open, Other Inputs = V _{SS}
I _{CC2}	V _{CC} supply current (nonvolatile write)			1	mA	f _{SCK} = 2MHz, SO = Open, Other Inputs = V _{SS}
I _{SB}	V _{CC} current (standby)			1	μA	SCK = SI = V _{SS} , Addr. = V _{SS} , CS = V _{CC}
I _{LI}	Input leakage current			10	μA	V _{IN} = V _{SS} to V _{CC}
I _{LO}	Output leakage current			10	μA	V _{OUT} = V _{SS} to V _{CC}
V _{IH}	Input HIGH voltage	V _{CC} × 0.7		V _{CC} + 0.5	V	
V _{IL}	Input LOW voltage	-0.5		V _{CC} × 0.1	V	
V _{OL}	Output LOW voltage			0.4	V	I _{OL} = 3mA

ENDURANCE AND DATA RETENTION

Parameter	Min.	Unit
Minimum endurance	100,000	Data changes per bit per register
Data retention	100	years

CAPACITANCE

Symbol	Test	Max.	Unit	Test Condition
C _{OUT} ⁽⁴⁾	Output capacitance (SO)	8	pF	V _{OUT} = 0V
C _{IN} ⁽⁴⁾	Input capacitance (A0, A1, SI, and SCK)	6	pF	V _{IN} = 0V

POWER-UP TIMING

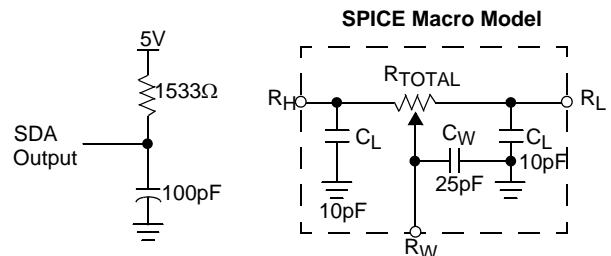
Symbol	Parameter	Min.	Max.	Unit
t _r V _{CC} ⁽⁶⁾	V _{CC} Power-up rate	0.2	50	V/ms
t _{PUR} ⁽⁵⁾	Power-up to initiation of read operation		1	ms
t _{PUW} ⁽⁵⁾	Power-up to initiation of write operation		5	ms

A.C. TEST CONDITIONS

Input pulse levels	V _{CC} × 0.1 to V _{CC} × 0.9
Input rise and fall times	10ns
Input and output timing level	V _{CC} × 0.5

- Notes:** (4) This parameter is periodically sampled and not 100% tested
 (5) t_{PUR} and t_{PUW} are the delays required from the time the (last) power supply (V_{CC}-) is stable until the specific instruction can be issued. These parameters are periodically sampled and not 100% tested.
 (6) This is not a tested or guaranteed parameter and should be used only as a guideline.

EQUIVALENT A.C. LOAD CIRCUIT



AC TIMING

Symbol	Parameter	Min.	Max.	Unit
f _{SCK}	SSI/SPI clock frequency		2.0	MHz
t _{CYC}	SSI/SPI clock cycle time	500		ns
t _{WH}	SSI/SPI clock high time	200		ns
t _{WL}	SSI/SPI clock low time	200		ns
t _{LEAD}	Lead time	250		ns
t _{LAG}	Lag time	250		ns
t _{SU}	SI, SCK, $\overline{\text{HOLD}}$ and $\overline{\text{CS}}$ input setup time	50		ns
t _H	SI, SCK, $\overline{\text{HOLD}}$ and $\overline{\text{CS}}$ input hold time	50		ns
t _{RI}	SI, SCK, $\overline{\text{HOLD}}$ and $\overline{\text{CS}}$ input rise time		2	μs
t _{FI}	SI, SCK, $\overline{\text{HOLD}}$ and $\overline{\text{CS}}$ input fall time		2	μs
t _{DIS}	SO output disable time	0	500	ns
t _V	SO output valid time		100	ns
t _{HO}	SO output hold time	0		ns
t _{RO}	SO output rise time		50	ns
t _{FO}	SO output fall time		50	ns
t _{HOLD}	$\overline{\text{HOLD}}$ time	400		ns
t _{HSU}	$\overline{\text{HOLD}}$ setup time	100		ns
t _{HH}	$\overline{\text{HOLD}}$ hold time	100		ns
t _{HZ}	$\overline{\text{HOLD}}$ low to output in high Z		100	ns
t _{LZ}	$\overline{\text{HOLD}}$ high to output in low Z		100	ns
T _I	Noise suppression time constant at SI, SCK, $\overline{\text{HOLD}}$ and $\overline{\text{CS}}$ inputs		20	ns
t _{CS}	$\overline{\text{CS}}$ deselect time	2		μs
t _{WPASU}	$\overline{\text{WP}}$, A0 and A1 setup time	0		ns
t _{WPAH}	$\overline{\text{WP}}$, A0 and A1 hold time	0		ns

HIGH-VOLTAGE WRITE CYCLE TIMING

Symbol	Parameter	Typ.	Max.	Unit
t _{WR}	High-voltage write cycle time (store instructions)	5	10	ms

XDCP TIMING

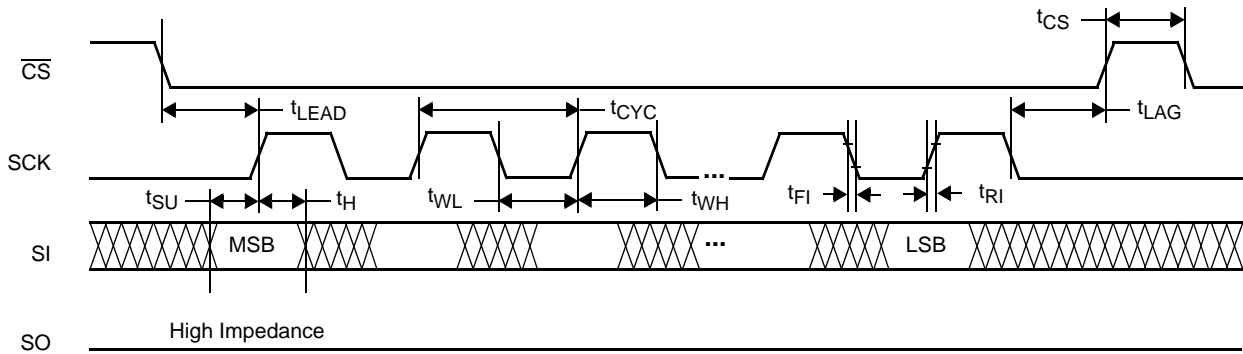
Symbol	Parameter	Min.	Max.	Unit
t _{WRPO}	Wiper response time after the third (last) power supply is stable		10	μs
t _{WRL}	Wiper response time after instruction issued (all load instructions)		10	μs
t _{WRID}	Wiper response time from an active SCL/SCK edge (increment/decrement instruction)		450	ns

SYMBOL TABLE

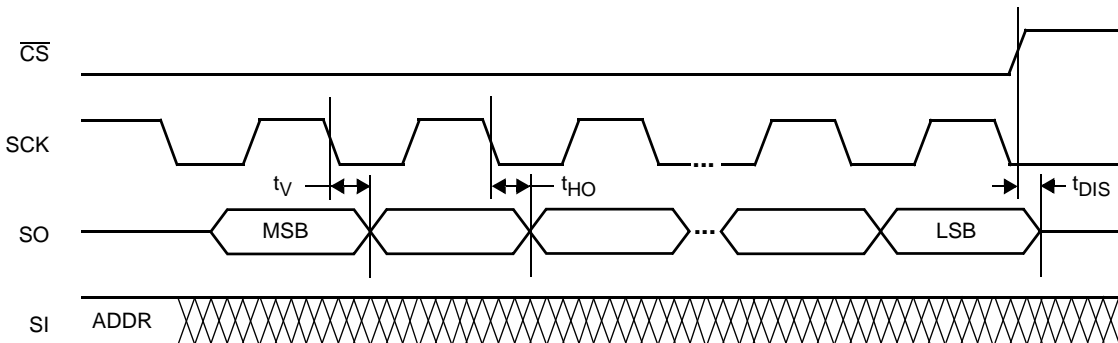
WAVEFORM	INPUTS	OUTPUTS
	Must be steady	Will be steady
	May change from Low to High	Will change from Low to High
	May change from High to Low	Will change from High to Low
	Don't Care: Changes Allowed	Changing: State Not Known
	N/A	Center Line is High Impedance

TIMING DIAGRAMS

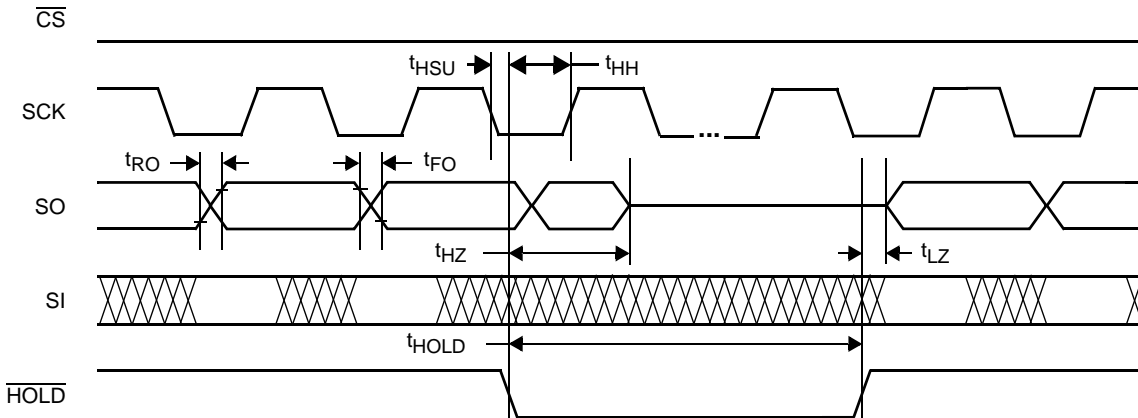
Input Timing



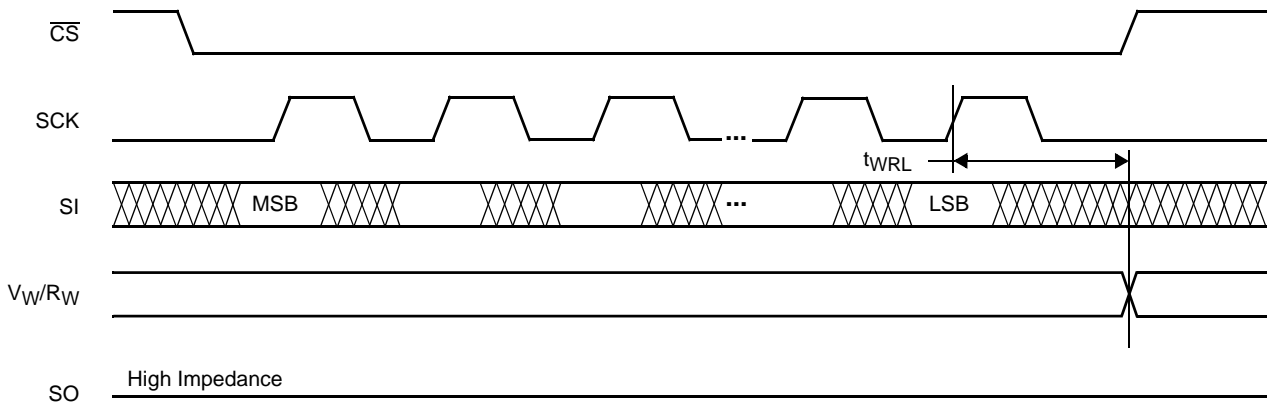
Output Timing



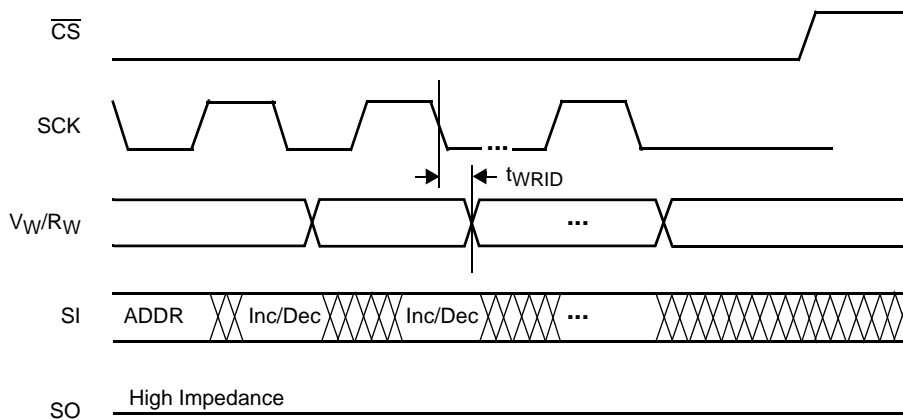
Hold Timing



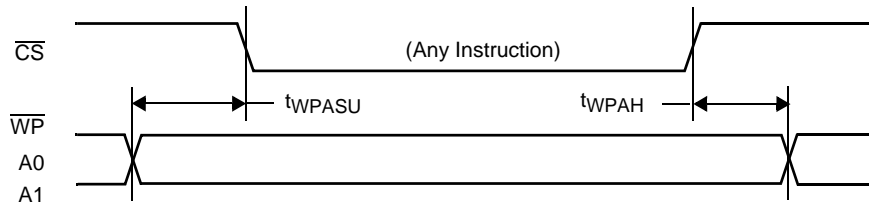
XDCP Timing (for All Load Instructions)



XDCP Timing (for Increment/Decrement Instruction)

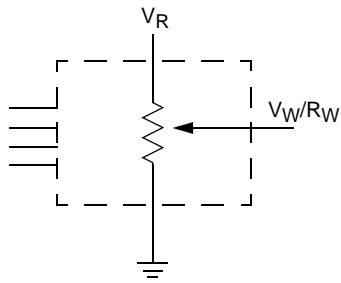


Write Protect and Device Address Pins Timing

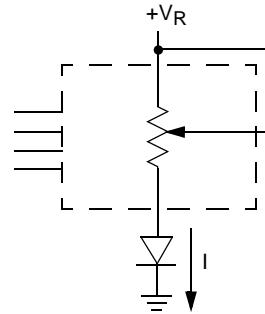


APPLICATIONS INFORMATION

Basic Configurations of Electronic Potentiometers



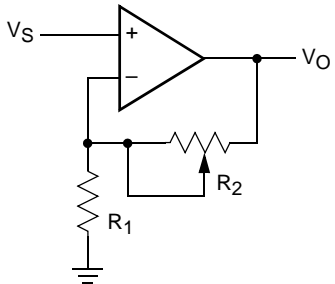
Three terminal Potentiometer;
Variable voltage divider



Two terminal Variable Resistor;
Variable current

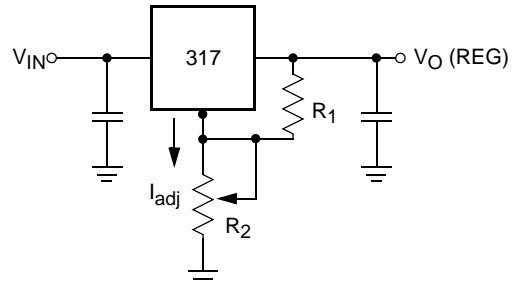
Application Circuits

Noninverting Amplifier



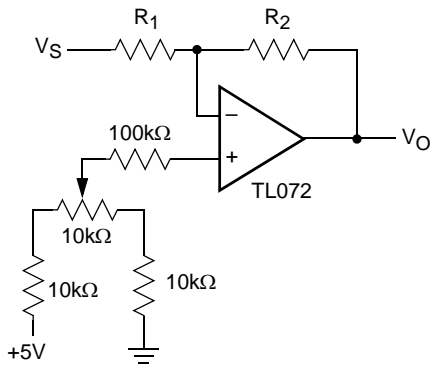
$$V_O = (1 + R_2/R_1) V_S$$

Voltage Regulator

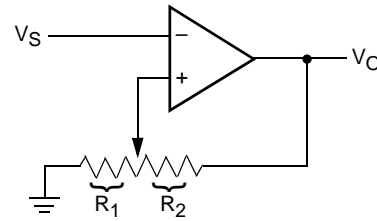


$$V_O (\text{REG}) = 1.25V (1 + R_2/R_1) + I_{\text{adj}} R_2$$

Offset Voltage Adjustment



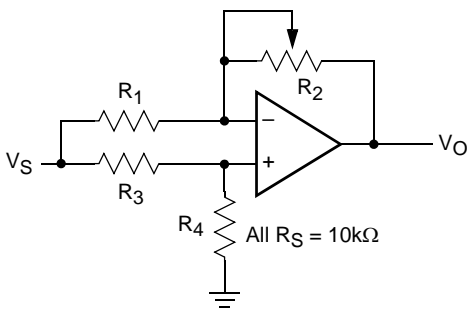
Comparator with Hysteresis



$$V_{UL} = \{R_1 / (R_1 + R_2)\} V_O(\text{max})$$

$$V_{LL} = \{R_1 / (R_1 + R_2)\} V_O(\text{min})$$

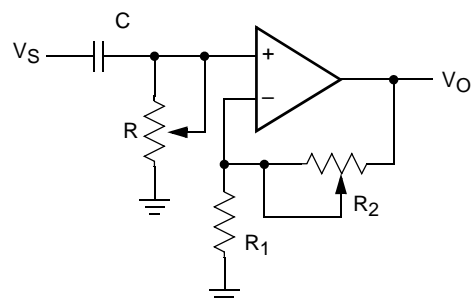
Attenuator



$$V_O = G V_S$$

$$-1/2 \leq G \leq +1/2$$

Filter

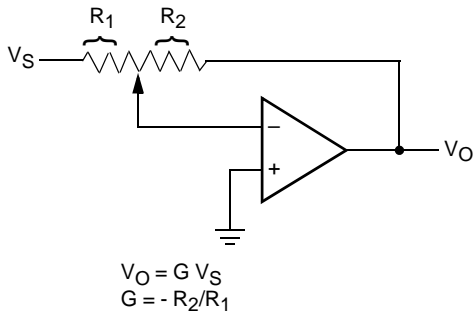


$$G_O = 1 + R_2/R_1$$

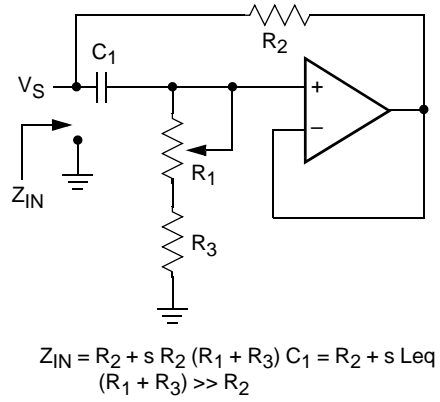
$$f_c = 1/(2\pi RC)$$

Application Circuits (continued)

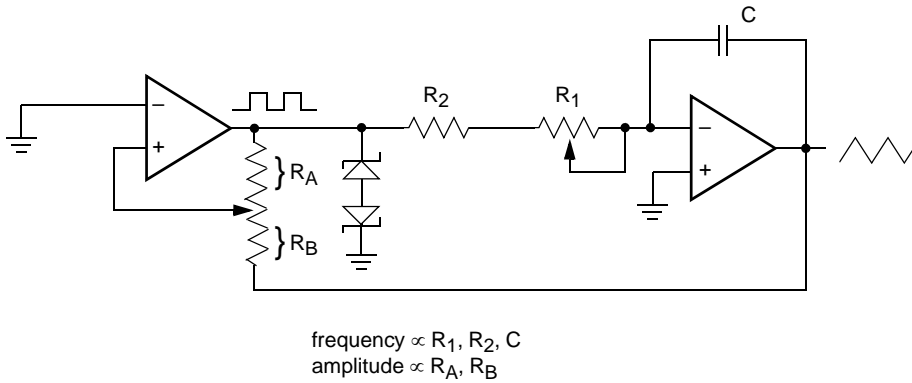
Inverting Amplifier



Equivalent L-R Circuit

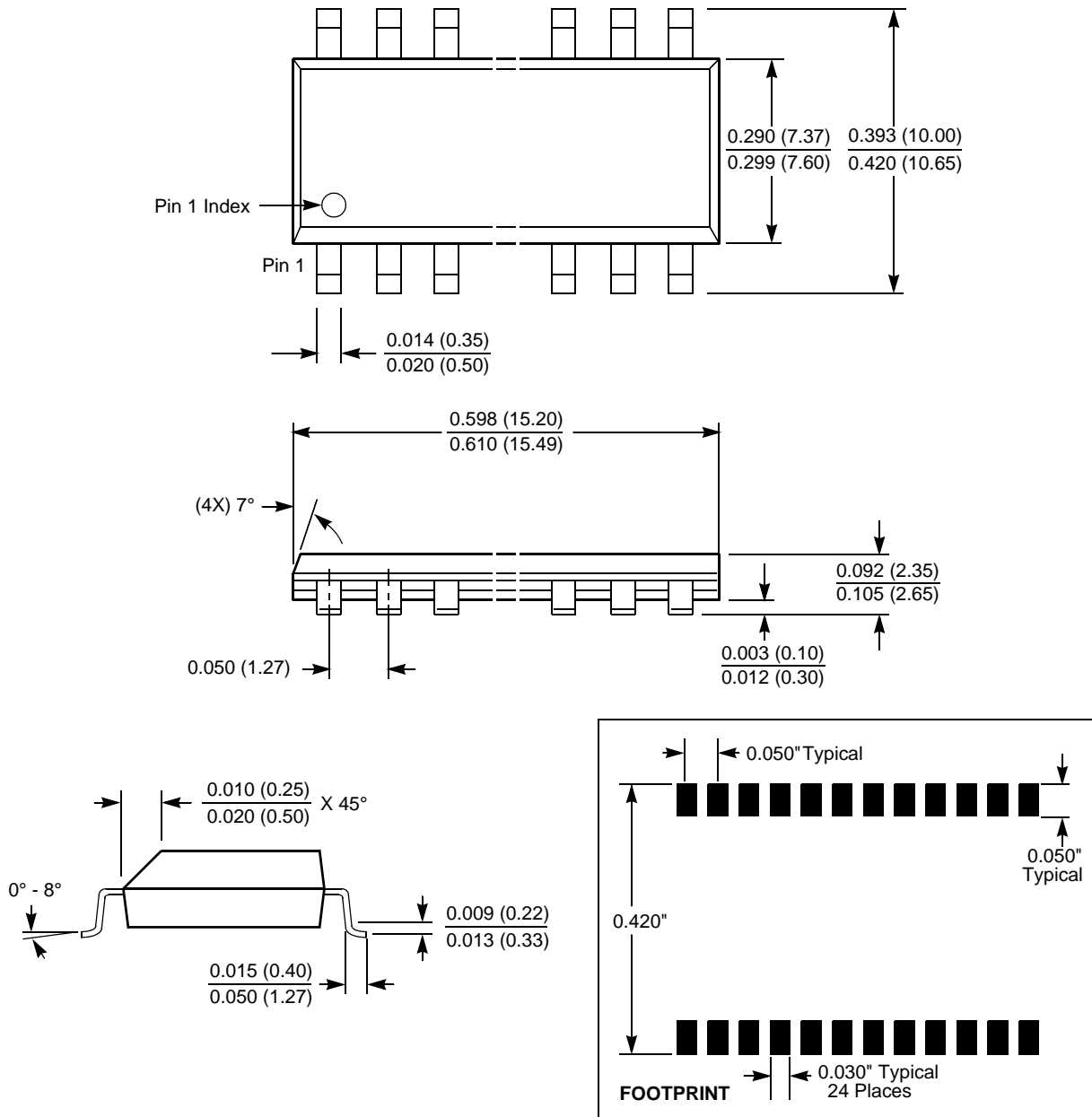


Function Generator



PACKAGING INFORMATION

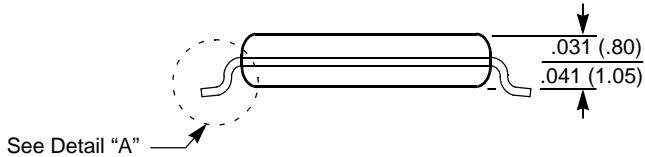
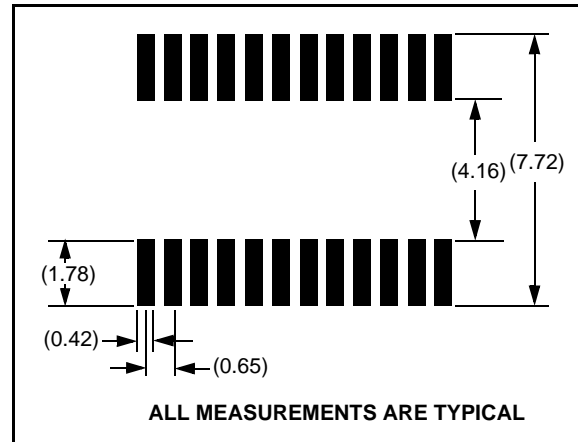
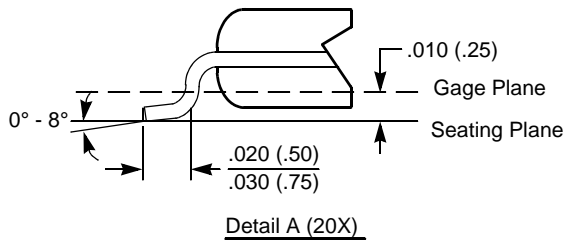
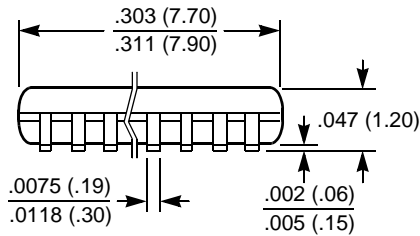
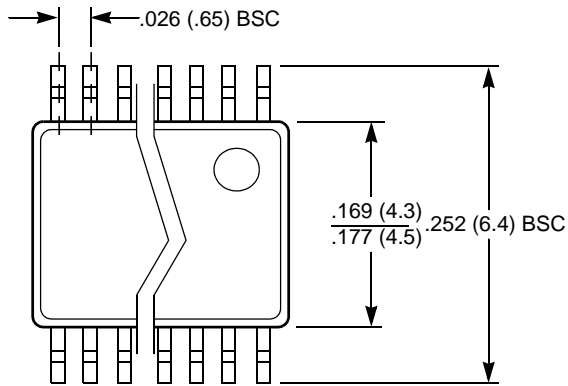
24-Lead Plastic Small Outline Gull Wing Package Type S



NOTE: ALL DIMENSIONS IN INCHES (IN PARENTHESES IN MILLIMETERS)

PACKAGING INFORMATION

24-Lead Plastic, TSSOP Package Type V



NOTE: ALL DIMENSIONS IN INCHES (IN PARENTHESES IN MILLIMETERS)

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